





Features

- Ultra Low g-Sensitivity
- Low Phase Noise
- High Stability
- Frequency Range: 8 MHZ to 15 MHZ
- Standard Frequency 10 MHz
- Vibration Compensation

Applications

- · Military Avionics
- · Airborne Radar
- Test Equipment
- Frequency Synthesizers
- Position Location
- Satellite Communications

Performance Specifications

Parameter	Min	Тур	Max	Units	Condition		
Available Frequencies							
Frequency Range	8		15	MHz			
G-Sensitivity Performance							
Standard crystal			1	ppb/g			
G Sensitivity w\ Low g-Crystal			0.2	ppb/g			
G Sensitivity w\ Low g-Crystal & Vibration compensation			0.02	ppb/g	Degrades to 0.2 ppb/g above 250 Hz		
(No mechanical resonances out to 2KHz) G sensitivity specified per axis							
For oscillators with 0.1 ppb/g out to 2 KHz contact factory.							
Frequency Stabilities (Stabilities listed for 10 MHz, For Stabilities above 10 MHz valves may degrade. Please contact factory.)							

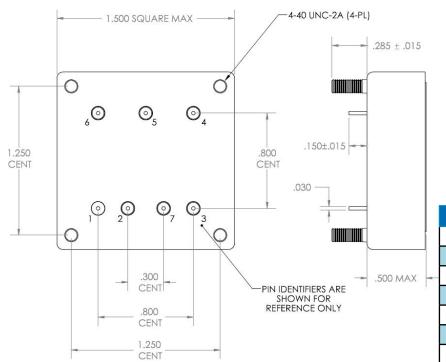
(Stabilities listed for 10 MHz. For Stabilities above 10 MHz values may degrade. Please contact factory.) -40... +85°C vs. Operating Temperature Range -30 +30 ppb (referenced to +25°C) -20 -40... +70°C +20 ppb -20... +70°C -10 +10 ppb 0... +70°C -5 +5 ppb **Initial Tolerance** -50 +50 at time of shipment, nominal EFC ppb vs. Supply Voltage Change -2.0 +2.0 $Vs \pm 5\%$ ppb vs. Load Change -2.0 +2.0 ppb Load ± 5% vs. Aging / Daily -0.5 +0.5 after 72 hours of operation ppb vs. Aging / 1st Year -40 after 72 hours of operation +40 ppb vs. Aging / Year (following years) -30 +30 ppb ppb Retrace² -20 +20

Performance Specifications

Parameter	Min	Тур	Max	Units	Condition	
Supply Voltage (Vs)						
Supply voltage	11.4	12.0	12.6	VDC		
Oven Power Consumption			100	Watts	during warm-up all temperatures	
			3.0	Watts	steady state @ +25°C	
			7.0	Watts	steady state @ -40°C	
			1.0	Watts	steady state @ +70°C	
RF Output						
Start Time		1	2	S	time required to achieve 90% of amplitude	
Signal		Sinewave				
Load		50		Ohm		
Output Power	+6.0	+7.0	+8.0	dBm		
Harmonics			-30	dBc		
		Freque	ncy Tun	ing (EFC)		
Tuning Range	±0.5	±0.8	±2.0	ppm	Electronic frequency control	
Linearity			20	%		
Tuning Slope		Pc	sitive			
Control Voltage Range	0.0	+4.0	+8.0	VDC		
Input Impredance	20			kOhm		
Modulation Bandwidth	150			Hz		
Phase Noise						
Phase Noise ³ standard(@ 10 MHZ) (under static conditions - no vibration)		-100 -130 -155 -166 -168	-95 -127 -152 -163 -165	dBc/Hz dBc/Hz dBc/Hz dBc/Hz dBc/Hz	1 Hz 10 Hz 100 Hz 1 KHz 10 KHz	

Parameter	Min	Тур	Max	Units	Condition		
Additional Parameters ¹							
Weight			100	g			
Absolute Maximum Ratings							
Supply voltage (Vs)			28	V			
Output Load	25		open	ohm			
Operable Temperature Range	-55		+85	°C			
Environmental Specifications							
Shock (Operating)	MIL-STE)-202, Me	thod 213	, Condition	J, 30G, 11ms, half sine		
Shock (Endurance)	Mil-STD-202, Method 213, Condition C, 100G, 6ms, half sine						
Sine Vibration (Operating)	Mil-STD-202, Method 204, Condition C, 10 G						
Sine Vibration (Endurance)	Mil-STD-202, Method 204, Condition D, 20 G						
Random Vibration (Operating)	Mil-STD-202, Method 214, Condition I-C, 9.26 Grms (without vibe comp) Mil-STD-202, Method 214, Condition I-A, 5.35 Grms (with vibe comp)						
Random Vibration (Endurance)	Mil-STD-202, Method 214, Condition I-H, 29.28 Grms						
Seal	Mil-STD)-202, Me	thod 112	, Condition I	D		
Humidity	MIL-STD-202, Method 103, Condition B, 90% rh						
Altitude	MIL-STD-202, Method 105, sea level to 30,000 ft						
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition A,B,C						
RoHS	not RoHS compliant						
Terminal Strength	MIL-STD-202, Method 211, Condition C (5 bends at 45°, 2 lbs)						
Moisture Sensitivity Level	1						
Storage Temperature Range	-55		+125	°C			

Outline Drawing / Enclosure

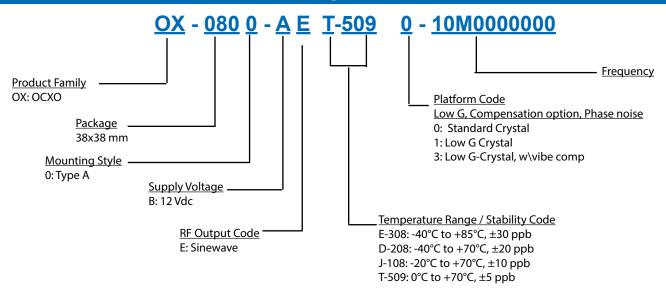


Dimensions in inches

Package configuration A				
ordering code	Height "H"			
0	0.50			

	Pin Connections
1	Ground (Case)
2	RF Output
3	Electronic Frequency Control (EFC)
4	Supply Voltage
5	Microsemi Internal Use Only / NC
6	Supply Voltage
7	Microsemi Internal Use Only / NC

Ordering Information⁴



Additional Ordering Options

Additional ordering options available include custom temperature ranges, custom temperature stabilities, custom phase noise requirements, custom height, custom supply voltage, and improved g-sensitvity. These modifications require a custom dash number - please contact the factory for additional information.

Design Tools

Microsemi stocks the following items for small orders and prototype development:
None
Microsemi stocks the following evaluation board for this product:
None
Application Notes:
None

Notes:

- 1. Unless otherwise stated, all values are valid after warm-up time and refer to typical conditions for supply voltage, frequency control voltage, load, and temperature (25°C).
- 2. Retrace is defined as the frequency difference between the end of two 24 hour on power periods with a 24 hour off period in between while at a constant temperature.
- 3. Phase noise degrades with increasing output frequency.
- 4. Not all options and codes available at all frequencies.



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